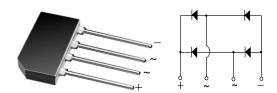


Vishay General Semiconductor

Glass Passivated Single-Phase Bridge Rectifier



Case Type GBL

PRIMARY CHARACTERISTICS							
I _{F(AV)} 4 A							
V_{RRM}	50 V to 1000 V						
I _{FSM}	150 A						
I _R	5 μΑ						
V _F	1.0 V						
T _J max.	150 °C						

FEATURES





Ideal for printed circuit boards

(e3)

• High surge current capability

ROHS

Typical I_R less than 0.1 μA

High case dielectric strength

• Solder dip 260 °C, 40 s

 Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

General purpose use in ac-to-dc bridge full wave rectification for monitor, TV, printer, SMPS, adapter, audio equipment, and home appliances application.

MECHANICAL DATA

Case: GBL

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class

1A whisker test

Polarity: As marked on body

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)									
PARAMETER	SYMBOL	GBL005	GBL01	GBL02	GBL04	GBL06	GBL08	GBL10	UNIT
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	200	400	600	800	1000	٧
Maximum RMS voltage	V _{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	V
$ \begin{array}{ll} \mbox{Maximum average forward rectified} & T_{\mbox{C}} = 50 \ ^{\circ}\mbox{C} \\ \mbox{output current at} & T_{\mbox{A}} = 40 \ ^{\circ}\mbox{C} \\ \end{array} $	I _{F(AV)}	4.0 ⁽¹⁾ 3.0 ⁽²⁾							Α
Peak forward surge current single sine-wave superimposed on rated load	I _{FSM}	150							Α
Rating for fusing (t < 8.3 ms)	l ² t		93						A ² s
Operating junction and storage temperature range	T _J , T _{STG}	TG - 55 to + 150				°C			

Notes:

- (1) Unit mounted on 3.0 x 3.0 x 0.11" thick (7.5 x 7.5 x 0.3 cm) aluminum plate
- (2) Unit mounted on P.C.B. at 0.375" (9.5 mm) lead length and 0.5 x 0.5" (12 x 12 mm) copper pads

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)										
PARAMETER	TEST CONDITIONS	SYMBOL	GBL005	GBL01	GBL02	GBL04	GBL06	GBL08	GBL10	UNIT
Maximum instantaneous forward voltage drop per diode	4.0 A	V _F	1.00					V		
Maximum DC reverse current at rated DC blocking voltage per diode	T _A = 25 °C T _A = 125 °C	I _R	5.0 500				μΑ			
Typical junction capacitance per diode	4.0 V, 1 MHz	СЈ		9	5			40		pF

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL GBL005 GBL01 GBL02 GBL04 GBL06 GBL08 GBL10 U					UNIT
Typical thermal resistance	$R_{ hetaJA} \ R_{ hetaJC}$	22 ⁽²⁾ 3.5 ⁽¹⁾			°C/W	

Notes:

- (1) Unit mounted on 3.0 x 3.0 x 0.11" thick (7.5 x 7.5 x 0.3 cm) aluminum plate
- (2) Unit mounted on P.C.B. at 0.375" (9.5 mm) lead length and 0.5 x 0.5" (12 x 12 mm) copper pads

ORDERING INFORMATION (Example)								
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE				
GBL06-E3/45	2.18	45	20	Tube				
GBL06-E3/51	2.18	51	400	Anti-static PVC tray				

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

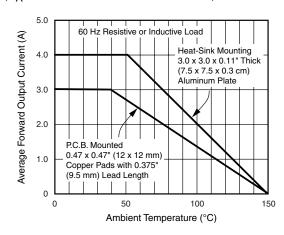


Figure 1. Derating Curves Outzput Rectified Current

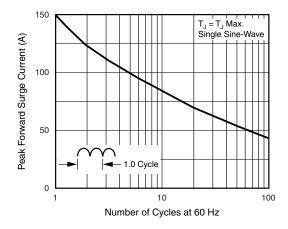


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current Per Diode



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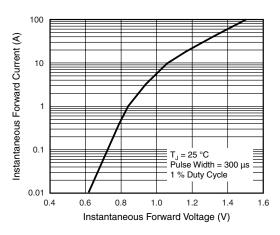


Figure 3. Typical Forward Voltage Characteristics Per Diode

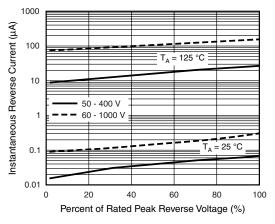


Figure 4. Typical Reverse Characteristics Per Diode

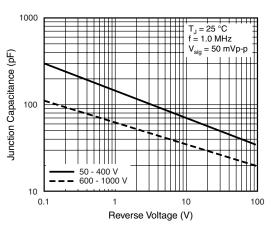


Figure 5. Typical Junction Capacitance Per Diode

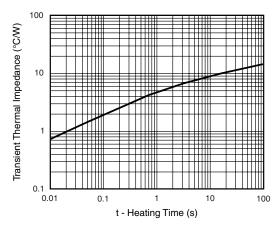


Figure 6. Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

Case Type GBL 0.825 (20.9) 0.815 (20.7) 0.125 (3.17) x 45° Chamfer 0.421 (10.7) 0.080 (2.03) 0.060 (1.50) 0.098 (2.5) 0.075 (1.9) 0.095 (2.41) 0.718 (18.2) 0.080 (2.03) 0.682 (17.3) 0.098 (2.5) Lead Depth 0.075 (1.9) 0.022 (0.56) 0.050 (1.27) 0.018 (0.46) 0.040 (1.02) 0.210 (5.3) 0.190 (4.8) 0.040 (1.02) 0.026 (0.66) 0.030 (0.76) + + 0.140 (3.56) 0.128 (3.25) 0.020 (0.51)

Polarity shown on front side of case, positive lead beveled corner

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